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All-optical Helicity-Independent Switching State Diagram in Gd-Fe-Co Alloys

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Ultrafast magnetization switching induced by a single femtosecond laser pulse, under no applied magnetic field, has attracted a lot of attention in the last 10 years because of its high potential for low-energy and ultrafast memory applications. Single-pulse helicity-independent switching has mostly been demonstrated for Gd-based materials. It is now necessary to optimize the pulse duration and the energy needed to switch a Gd-Fe-Co magnet depending on the alloy thickness and composition. Here we experimentally report state diagrams showing the magnetic state obtained after one single pulse depending on the laser pulse duration and fluence for various Gd-Fe-Co thin films with different compositions and thicknesses. We demonstrate that these state diagrams share similar characteristics: the fluence window for switching narrows for longer pulse duration and for the considered pulse-duration range the critical fluence for single-pulse switching increases linearly as a function of the pulse duration while the critical fluence required for creating a multidomain state remains almost constant. Calculations based on the atomistic spin model qualitatively reproduce the experimental state diagrams and their evolution. By studying the effect of the composition and the thickness on the state diagram, we demonstrate that the best energy efficiency and the longest pulse duration for switching are obtained for composition around the magnetic compensation.

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I. INTRODUCTION

The rapidly increasing social needs for digital information drive the development of magnetic recording technology. In magnetic memory devices, digital information is stored by setting the magnetization of storage medium either “up” or “down.” The data writing speed is therefore determined by how fast the setting process could be achieved [1–3]. The conventional way to switch the magnetization is by applying a magnetic field, which normally requires high power consumption and complex circuit design [4,5]. Later, various methods for manipulating the magnetization without the magnetic field emerged continuously, including strain [6,7], electric field [8,9], heat [10,11], and polarized current [12,13]. However, the switching process in above cases usually happens via a coherent damping precession of the spins [14,15]. The frequency of the precession is normally in the GHz range and the reorientation process can take several nanoseconds [16,17]. Therefore, a faster writing method is increasingly pursued by researchers.

Concerning the effect of ultrashort light pulse on magnetization, the field opened in 1996 with the discovery of ultrafast demagnetization of a Ni film by a 60-fs optical laser pulse [18]. A decade later, Stanciu et al. [19] demonstrated the possibility of using circular femtosecond laser pulses to induce ultrafast magnetization switching in Gd-Fe-Co, namely all-optical switching (AOS), which not only removes the need for magnetic field but also drives writing time towards the picosecond timescale. Soon after, it was discovered that a single linearly polarized pulse is sufficient to switch the Gd-Fe-Co, which is called all-optical helicity-independent switching (AO HIS) [20,21].

The mechanism behind AO HIS in Gd-Fe-Co alloys has been explained by the presence of two magnetization sublattices with two different relaxation times leading to a transient ferromagnetic-like state [20]. Later, Gorchon et al. studied the role of electron and phonon temperatures in AO HIS [22]. According to these works, the laser fluence should be high enough to sufficiently heat the free electrons, and initiate the demagnetization and switching process. On the other hand, the laser fluence should also ensure that the phonon temperature $T_{ph}$ remains below $T_C$, since crossing $T_C$ would lead to magnetic disorder and the final magnetization state would then be determined by the

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cooling conditions. Therefore, AO HIS should occur only within a narrow range of pulse fluence. In addition, the pulse duration is another useful laser parameter. As mentioned above, high $T_c$ is essential for AOS, so it is predicted that the maximum pulse duration ($\tau_{\text{max}}$) should be on the timescale of the electron-lattice interaction $\tau_{e-l}$ (around 2 ps in Gd-Fe-Co [23]) in order to reach an overheating of the electrons. However, AOS with a pulse duration up to 15 ps was reported [22]. Moreover, two recent works on AO HIS in Gd-Fe-Co have demonstrated that $\tau_{\text{max}}$ is significantly influenced by the Gd concentration [23,24].

Despite several works investigating the effect of single-shot AO HIS, the influence of the laser parameters such as fluence and pulse duration and the properties of the Gd-Fe-Co sample such as the concentration and the thickness, has not been systematically investigated. In this work, we report the AO HIS state diagrams for Gd-Fe-Co thin films for different compositions and thicknesses by determining the magnetic configuration as a function of laser-pulse duration and fluence. These state diagrams allow us to identify the ideal material and beam parameters to obtain an energy-efficient switching. We also define the critical switching fluence ($F_{\text{switch}}^C$) as the minimum fluence allowing the switching of a given alloy thin film. It is usually obtained for the shortest pulse duration. We demonstrate that $F_{\text{switch}}^C$ reaches a minimum around the magnetization compensation point. The state diagram is also significantly influenced by the sample thickness. A thinner film allows the maximum pulse duration necessary to be increased to achieve AO HIS. These findings on the influence of the laser parameters and thin-film properties on AO HIS allow a better understanding of the fundamental mechanism behind this switching.

II. RESULTS

A. Sample structure and characterization

We prepare a series of 10- and 20-nm-thick Gd$_x$ (FeCo)$_{100-x}$ layers with different Gd concentrations ranging from 22 to 27%. The amorphous alloys are ferrimagnetic metallic materials, with two antiferromagnetically exchange-coupled sublattices. The net magnetization of the alloy is given by the sum of the transition metal (FeCo) sublattice magnetization and the rare-earth (Gd) sublattice magnetization. Therefore, by tuning the composition of the Gd$_x$ (FeCo)$_{100-x}$, it is possible to modulate the magnetic properties. For a composition called the magnetization compensation point ($x = x_{\text{comp}}$), the net magnetization reaches zero and the coercivity diverges.

The investigated samples are deposited by dc magnetron sputtering onto a glass substrate according to the following multilayered structure: glass/Ta (3 nm)/Pt (5 nm)/Gd$_x$ (FeCo)$_{100-x}$ (t nm)/Ta (5 nm). The thin Ta capping layer on top prevents the oxidation of the magnetic film, while it allows probing of the magnetic properties via magneto-optical Kerr effect (MOKE). The bottom Ta layer improves adhesion of the structure to the glass substrate. According to the magnetic hysteresis loops obtained by MOKE, all studied samples show strong perpendicular magnetic anisotropy (PMA). From the MOKE results, at room temperature, we could determine $x_{\text{comp}}$ between 24% and 25% (MOKE results are provided in Note S1 within the Supplemental Material [25]). The net magnetic moment is thus aligned in the direction of the FeCo magnetization sublattice below $x_{\text{comp}}$ while it changes its sign and becomes aligned with the Gd magnetization sublattice above $x_{\text{comp}}$. Note that $x_{\text{comp}}$ also depends on the temperature.

B. Magnetization state diagram of Gd-Fe-Co

Figure 1(a) shows magneto-optical images obtained on a 20-nm Gd$_{24}$ (FeCo)$_{76}$ film after exposure to a single laser pulse for different pulse durations (50 fs, 1 ps, and 3 ps) and different fluences. The film is initially saturated under an external magnetic field before exposure. We observe that above a certain fluence defined as $F_{\text{switch}}$, the magnetization of the Gd-Fe-Co switches (evidences of AO HIS for the studied samples are supplied in Note S2 within the Supplemental Material [25]). Moreover, the spot showing AO HIS expands as the fluence increases and a similar trend is shown for different pulse durations. It is clear that $F_{\text{switch}}$ depends on the pulse duration. For fluences lower than $F_{\text{switch}}$, the laser has no effect on the magnetic configuration (not shown). Above a given fluence $F_{\text{multi}}$, multiple domains start to appear in the middle of the spot. Consequently, AO HIS is only observed for a fluence value between $F_{\text{switch}}$ and $F_{\text{multi}}$. In addition, as displayed in Fig. 1(b), fully demagnetized patterns are only found when the pulse duration increases to 4 ps, indicating that deterministic all-optical switching could not be achieved above certain pulse duration whatever the laser fluence. Note that the AO HIS state diagram is very different from that of all-optical helicity-dependent switching (AO HDS) such as the one obtained by Kichin et al. [26]. Indeed, for AO HIS the fluence window for switching narrows as the pulse duration increases, which is opposite to the trend observed for AO HDS for which the fluence window broadens as the pulse duration increases. This is one more proof that the mechanism behind the two types of switching (AO HIS and AO HDS) are different [27].

To gain a more detailed insight of the dependence of AO HIS on the pulse characteristics, $F_{\text{switch}}$ and $F_{\text{multi}}$ are presented as a function of the pulse duration indicated by full blue squares and full red dots, respectively, as shown in Fig. 1(c). The open black squares indicate the $F_{\text{switch}}$ obtained via the method proposed by Liu et al. [28]. A full description of this technique is supplied in Note S2 within the Supplemental Material [25]. This AO HIS
state diagram allows defining the single-pulse laser characteristics leading to AO HIS, multidomain state or no reversal. Moreover, $F_{\text{switch}}$ and $F_{\text{multi}}$ show obviously different dependences on pulse duration. $F_{\text{multi}}$ is independent on the pulse duration in this pulse-duration range, whereas $F_{\text{switch}}$ shows in first approximation a linear increase as the pulse duration increases until $F_{\text{switch}} = F_{\text{multi}}$, which defines the maximum pulse duration ($\tau_{\text{max}}$) for which AO HIS can be observed. Increasing further the pulse duration leads only to a multidomain state.

C. AO HIS state diagrams as a function of the Gd concentration

Figures 2(a) and 2(b) present AO HIS state diagrams for 20-nm Gd$_x$(FeCo)$_{100-x}$ films, with $22 \leq x \leq 27$ [see Fig. S7 within the Supplemental Material for state diagrams [25] in 10-nm Gd$_x$(FeCo)$_{100-x}$]. One can see that the switching regions for different samples share similar outlines (highlighted by colored dashed lines). Indeed, for all concentrations, $F_{\text{switch}}$ increases linearly with the pulse duration and $F_{\text{multi}}$ is independent of the pulse duration. However, obvious changes can be found as the composition is varied. For a more quantitative analysis, the switching region in the state diagram can be characterized by a right triangle. It is mathematically determined by the smallest switching fluence $F_{\text{switch}}^C$ (the $x$-axis intercept of linear fit of $F_{\text{switch}}$), $F_{\text{multi}}$, and the slope $k$ describing the dependence of $F_{\text{switch}}$ on pulse duration. It is seen that $F_{\text{switch}}^C$ shows a minimum around 25% Gd concentration, which is near the magnetization compensation point $x_{\text{comp}}$. The slope $k$ increases with the Gd concentration while $F_{\text{multi}}$ decreases, which can be attributed to the reduction of the Curie temperature with the Gd composition [24]. We then observe that the fluence range showing AO HIS is larger and the maximum pulse duration ($\tau_{\text{max}}$) is longer around $x_{\text{comp}}$. A complete AOS is observed for laser pulse durations up to 3.8 ps for Gd$_{25}$(FeCo)$_{75}$. This contradicts the trend predicted by Davis et al. that $\tau_{\text{max}}$ linearly increases with the Gd concentration [23]. Figure 3 quantitatively shows $F_{\text{switch}}^C$ and $k$ as a function of the Gd concentration derived from the AO HIS state diagrams. It is seen that $F_{\text{switch}}^C$ and $k$ share similar trends in 10- and 20-nm samples. However, $F_{\text{switch}}^C$ scales with the layer thickness as shown in Fig. 3(a); a larger $k$ is obtained for 10-nm Gd-Fe-Co at a fixed composition as shown in Fig. 3(b). As a consequence, a complete AO HIS is observed in 10-nm Gd$_{25}$(FeCo)$_{75}$ for a pulse duration up to 11.8 ps, which is consistent with the observation of AO HIS for a 14-nm Gd-Fe-Co layer and a pulse duration around 10 ps [22]. The state diagrams for 10-nm samples are provided in Note S3 within the Supplemental Material [25].

D. Atomistic modeling for single-shot AO HIS

In this section, our goal is to test if atomistic modeling can reproduce the experimental results shown above. In the atomistic calculations, each spin is coupled to the
temperature of the electron thermal bath. Due to the small heat capacity of electrons, the action of the ultrashort laser pulse first induces a rapid increase of the electron temperature, followed by a slow heat exchange between the electron and phonon thermal baths until equilibrium is reached. The temporal evolution of the electron temperature $T_e$ and the phonon temperature $T_{ph}$ are described by the two-temperature model described in Ref. [29]. To simplify calculations, Fe and Co are considered as one sublattice and share the same parameters taken from Refs. [30–32]. Simulations are performed using the VAMPIRE software package [33].

We then simulate the temporal evolution of magnetization of Gd and FeCo to an ultrafast light pulse (see Note S4 within the Supplemental Material [25]). Here, we determine the magnetization state after laser excitation according to the value of the $z$ component of FeCo magnetization $m_{FeCo}^z(t)$ when $t = 20$ ps: (1) switching [$m_{FeCo}^z(20) \leq -0.1$], (2) multidomain [$-0.1 < m_{FeCo}^z(20) < 0.1$], (3) no switching [$m_{FeCo}^z(20) \geq 0.1$]. We choose “20 ps” to allow for magnetization recovery. Based on such a definition, we obtain the simulated state diagram as shown in Fig. 4. It is seen that $F_{\text{switch}}$ greatly increases from 5.16 mJ/cm$^2$ at 50 fs to 7.92 mJ/cm$^2$ at 1 ps while only a little change could

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**FIG. 2.** AO HIS state diagrams of 20 nm Gd$_x$(FeCo)$_{100-x}$ for (a) $22 \leq x \leq 25$ and (b) $25 \leq x \leq 27$. The switching regions for different Gd concentrations are highlighted by colored dashed lines. They are mathematically determined by the smallest switching fluence $F_{\text{switch}}^C$ (the $x$-axis intercept of linear fit of $F_{\text{switch}}$), $F_{\text{multi}}$ and the slope $k$ describing the dependence of $F_{\text{switch}}$ on pulse duration.

**FIG. 3.** Quantitative description of the key features of AO HIS Gd$_x$(FeCo)$_{100-x}$ state diagrams. (a) The critical switching fluence $F_{\text{switch}}^C$ obtained from the intercept of linear fit of $F_{\text{switch}}$ on the $x$ axis is plotted as a function of Gd concentration. (b) Evolution of the slope $k$ extracted from the linear fit of $F_{\text{switch}}$ as a function of Gd concentration.
be observed in $F_{\text{multi}}$, which agrees well with the experimental state diagram. As the pulse broadens, the increase in $F_{\text{switch}}$ is necessary for achieving an overheating of the free electrons, which seems to be crucial for AO HIS. In addition, we calculate the temporal evolution of phonon temperature $T_{\text{ph}}$ at $F_{\text{multi}}$ for different pulse durations (see Note S4 within the Supplemental Material [25]). Interestingly, the peak $T_{\text{ph}}$ shows almost no change for different pulse durations. As a consequence, it depends mostly on the pulse energy and reaches $T_c$ at a very similar fluence for different pulse durations.

Then we try to plot $k$ for different Gd concentrations. As shown in Fig. 5(a), we calculate $F_{\text{switch}}$ for several pulse durations and compositions. The slope $k$ derived from the linear fit shows a monotonically increase with Gd concentration as presented in Fig. 5(b). This indicates that when the pulse duration increases by a certain amount, the rise in $F_{\text{switch}}$ required to induce AO HIS is smaller for the samples with more Gd. This is likely because that the laser heating has a more significant effect with the increased Gd content due to the reduction in Curie temperature $T_C$. Lastly, we calculate $F_{\text{switch}}$ as a function of Gd concentration for 50-fs pulse duration. As displayed in Fig. 5(c), $F_{\text{switch}}$ depends significantly on the Gd concentration, and reaches a minimum around 32% Gd. This trend is quite similar to the one observed in the experiments. However, the calculated $x_{\text{comp}}$ is around 26 (see Note S4 within the Supplemental Material [25]), which differs from the composition where the minimum $F_{\text{switch}}$ is obtained. This shift could be explained by a very recent work, which shows the position of the $F_{\text{switch}}$ minimum with respect to the Gd-concentration varies with the ratio $\alpha_{\text{Fe}}/\alpha_{\text{Gd}}$ utilized in the atomistic modeling [24].

III. DISCUSSION

The experimental AO HIS state diagrams allow to quickly visualize the laser-pulse conditions (fluence and pulse duration) required for single-shot AO HIS. We can then determine the evolution of the state diagrams as a function of the Gd-Fe-Co alloy concentration and thickness. This experimental study helps to address technologically relevant controversy and provides crucial guidelines to engineer energy-efficient and technologically feasible single-pulse all-optical switching of magnetization (a detailed discussion is provided in Note S5 within the Supplemental Material [25]). Since it has already been shown that both single femtosecond light pulse and single femtosecond hot electron pulse [34] can induce AO HIS, the next issue is to generalize the effect to longer pulses to be technologically compatible with feasible electronics. Our study allows answering two controversial questions: how can we optimize the material and the laser excitation to obtain a low-energy AO HIS and how can we observe AO HIS for long pulse duration?

FIG. 4. Simulated state diagram for Gd$_{26}$(FeCo)$_{74}$. Blue squares and red dots indicate $F_{\text{switch}}$ and $F_{\text{multi}}$, respectively. Dashed lines show linear fits.

FIG. 5. Quantitative description of the key features of simulated AO HIS Gd$_x$(FeCo)$_{100-x}$ state diagrams. (a) Simulated slopes describing the dependence of $F_{\text{switch}}$ on pulse duration for different Gd concentrations. Dashed lines are the linear fits. (b) Slope $k$ as a function of Gd concentration derived from the data shown in (a). (c) $F_{\text{switch}}$ as a function of Gd concentration for a pulse duration of 50 fs.
For the first question, initial studies proposed that the existence of magnetization compensation temperature $T_M$ is essential to achieve AO HIS in ferrimagnets [35]. Later, it was proved that $T_M$ is not indispensible while low net magnetization $M_{net}$ greatly promotes AO HIS [36]. However, a following theory work highlighted the relevance of temperature derivative of the magnetization $dM_{net}(T)/dT$ and it pointed out that the critical switching fluence is not the minimum at magnetization compensation point $x_{comp}$ [37]. In our study, we experimentally demonstrate that $F_{switch}^{C}$ significantly depends on the alloy composition and reaches a minimum around $x_{comp}$. We also find that $F_{switch}^{C}$ scales with the layer thickness, which can be ascribed to the variation of the laser absorption and the domain volume, indicating that a smaller thickness helps to develop energy-efficient AOS devices (more results are provided in Note S6 within the Supplemental Material [25]).

The second issue concerns the pulse-duration threshold $\tau_{max}$. As mentioned above, previous works highlight the relevance of dramatic overheating of electrons. Therefore, it is initially predicted that $\tau_{max}$ should be at the timescale of the electron-lattice interaction $\tau_{e-l}$ (around 2 ps in Gd-Fe-Co). However, further studies have shown disparate results ranging from 0.4 to 15 ps [22,23], which could appear surprising at first. In our work, we reveal that $\tau_{max}$ is determined by $F_{switch}^{C}$, which defines the base of the triangle-shaped switching region and the slope $k$, which describes the dependence of $F_{switch}$ on pulse duration and $F_{multi}$, which seems to be given by the material Curie temperature. To obtain the largest $\tau_{max}$ we should just aim for a small $F_{switch}^{C}$, a large $F_{multi}$ and a large $k$. However, $k$ increases with Gd concentration whereas $F_{multi}$ decreases with Gd concentration and $F_{switch}$ is minimum around the magnetic compensation alloy composition. Therefore, to maximize $\tau_{max}$ it is certainly interesting to be close to the compensation to obtain the smallest $F_{switch}^{C}$, but it is also interesting to play with the relative Fe and Co concentration in order to increase the alloys’ Curie temperature and increase $k$. In addition, a recent work on AO HIS in Gd-Tb-Co highlights that the damping of the rare earth site has an obvious influence on $F_{switch}$ [38]. Thus we propose that the magnetization state diagram could also be modified by adding different elements, which will be a subject of future work. The influence of the sample thickness on AO HIS is more complicated than it appears. From the state diagrams, the right triangle-shaped switching region for 10-nm Gd-Fe-Co possesses a much steeper slope than that for 20-nm Gd-Fe-Co, which results in a larger $\tau_{max}$. This difference is likely caused by the nonuniform light absorption with respect to the sample depth. Xu et al. have calculated the heat-absorption profile for similar 20-nm Gd-Fe-Co stacks [27]. They revealed that the electron temperature sharply decreases within the bottom 5-nm part of a 20-nm Gd-Fe-Co film when excited with a laser having a wavelength of 800 nm. Therefore, it needs much more energy to induce an overheating for thicker samples as pulse duration increases, leading to a smaller $k$.

IV. CONCLUSION

In conclusion, precise single-shot AO HIS state diagrams for various Gd$_x$(FeCo)$_{100-x}$ are built. It is found that the critical fluences for AO HIS and multidomain state exhibit different pulse-duration dependences. Calculations based on atomistic spin model are able to reproduce the behaviors observed experimentally. This reveals that electron temperature and lattice temperature play useful roles in the all-optical magnetization switching. In addition, we demonstrate that the dependence of the critical switching fluence on pulse duration can be tuned by changing the alloy composition and thickness. These results provide a way to enlarge the switching region of AO HIS, which will be of great significance for the application of AO HIS since the present semiconductor laser sources can only generate laser pulses with picosecond temporal width [39] where the fluence window for AO HIS is extremely narrow or even vanishes and the switching fluence is much larger than that for femtosecond laser pulse.

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[25] See Supplemental Material at http://link.aps.org/supplemental/10.1103/PhysRevApplied.15.054065 for more detailed information about the experiments, the MOKE results of all the studied samples, a brief discussion of the atomistic modeling, and further experimental and numerical results supporting our conclusions.


[33] VAMPIRE software package. Available from https://vampire.york.ac.uk/.


